

MOS INTEGRATED CIRCUIT $\mu PD4713A$

RS-232 LINE DRIVER/RECEIVER

The μ PD4713A is a high-voltage silicon gate CMOS line driver/reciever conforming to the EIA/TIA-232-E standard. It can operate with a single +5 V power source because it is provided with a DC-DC converter. In addition, this line driver/receiver has many ancillary functions, including output control, threshold select, and standby functions. Because the μ PD4713A is provided with three output driver circuits and three receiver circuits, it can constitute an RS-232 interface circuit with a single chip.

FEATURES

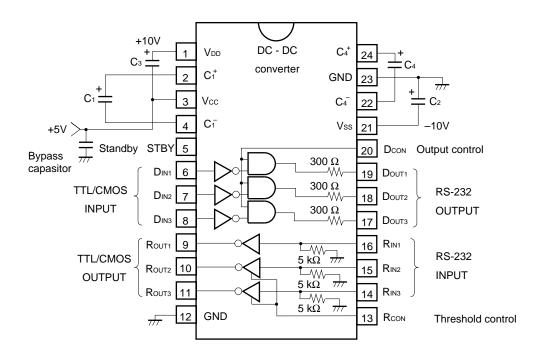
- Conforms to EIA/TIA-232-E (RS-232C) standard
- +5 V single power source
- Threshold select pin selecting two types of threshold voltages
- Standby mode can be set by making standby pin high to reduce circuit current.
- Three-state output configuration. Both driver and receiver outputs go into high-impedance state in standby mode.

ORDERING INFORMATION

Part Number	Package
μPD4713ACX	24-pin plastic DIP (300 mil)
μ PD4713AGT	24-pin plastic SOP (375 mil)



BLOCK DIAGRAM/PIN CONFIGURATION (Top View)



- * V_{DD} and V_{ss} are output pins of voltages internally boosted. Connecting a load directly to these pins is not recommended.
- ** The standby pin is internally pulled down.
- *** Use capacitors with a working voltage of 16 V or higher as C_1 through C_4 . Insert a bypass Capasitor about 0.1 to 1 μ F between Vcc pin to GND pin.



TRUTH TABLE

Drivers

STBY	Dcon	Din	D оит	Remark
Н	Х	Х	Z	Standby mode (DC-DC converter stops)
L	L	Х	L	Mark level output
L	Н	L	Н	Space level output
L	Н	Н	L	Mark level output

Receivers

STBY	Rin	Rоит	Remark
Н	Х	Z	Stanby mode (DC-DC converter stops)
L	L	Н	Mark level input
L	Н	L	Space level input

Receiver input threshold voltage

Rcon	R _{IN1}	RIN2 to RIN3
L	A mode	A mode
Н	A mode	B mode

H: high level, L: low level, Z: high impedance, X: H or L



ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Parameter	Symbol	Ratings	Unit
Supply voltage	Vcc	-0.5 to +6.0	V
Driver input voltage	Din	−0.5 to Vcc +0.5	V
Receiver input voltage	Rin	-30.0 to +30.0	V
Driver output voltage	D оит	-25.0 to +25.0 Note1	V
Receiver output voltage	Rоит	-0.5 to Vcc + 0.5	V
Receiver input current	lin	±60.0	mA
Operating temperature range	TA	-40 to +85	°C
Storage temperature range	T _{stg}	-55 to +150	°C
Power dissipation	PT	0.5	W

Note 1. Pulse width: 1 ms, duty factor: 10 % MAX.

RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply voltage	Vcc	4.5	5.0	5.5	V
Receiver input voltage	Rin	-25		+25	V
Operating temperature range	TA	-20		80	°C
External capacitance	Note 2	4.7		47	μF

Note 2. The capacitance of an electrolytic capacitor decreases at a low temperature (0 $^{\circ}$ C or lower). Determine the capacitance of the capacitor to be used taking this into consideration when the μ PD4713A is used at a low temperature. Keep the wiring length between the capacitor and IC as short as possible.



ELECTRICAL CHARACTERISTICS (OVERALL) (Unless otherwise specified, Vcc = +5 V \pm 10 %, T_A = -20 °C to +80 °C, C₁ to C₄ = 22 μ F)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Circuit current		Vcc = +5 V, no load, R _{IN} pin open				
	Icc1	(Standby pin open)		5.0	18.0	mA
Circuit current		$Vcc = +5 \text{ V}, \text{ RL} = 3 \text{ k}\Omega \text{ (Dout)}, \text{ DIN} = \text{GND},$				
	Icc2	RIN and ROUT pins open		21.0	40.0	mA
		(Standby pin open)				
Standby circuit current	Icc	Vcc = +5 V, no load, R _{IN} pin open			400	•
	(Standby)	(Standby pin high)		50	120	μΑ
Standby low-level	VIL	Note 3				
input voltage	(Standby)				8.0	V
Standby high-level	ViH					
input voltage	(Standby)		2.0			V
Standby high-level	Іін	Vcc = +5.5 V				
input current	(Standby)	V ₁ = 5.5 V			100	μΑ
Standby low-level	Iı∟	Vcc = +5.5 V			_	
input current	(Standby)	V1 = 0 V			-1	μΑ
Input capacitance		Driver input and receiver input			4.0	1
	Cin	Vcc = +5 V, vs. GND, f = 1 MHz			10	pF

^{*} TYP.: Typical (reference) value at $T_A = 25$ °C.

Note 3. Because the standby pin is internally pulled down, if the standby pin is left open, operating mode is in effect.

ELECTRICAL CHARACTERISTICS (DRIVER) (Unless otherwise specified, Vcc = +5 V ± 10 %, T_A = -20 °C to +80 °C, C₁ to C₄ = 22 μ F)

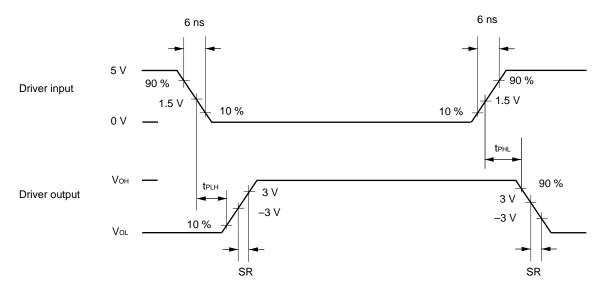
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Low-level input voltage	VIL				0.8	V
High-level input voltage	ViH		2.0			V
Low-level input current	lı∟		0		-1.0	μΑ
High-level input current	Іін		0		1.0	μΑ
Output voltage		Vcc = +5.0 V, R _L = ∞, T _A = 25 °C		±9.7		V
	VDO	$Vcc = +5.0 \text{ V}, \text{ RL} = 3 \text{ k}\Omega$	±5.5			V
		$Vcc = +4.5 \text{ V}, \text{ RL} = 3 \text{ k}\Omega$	±5.0			V
Output short current	Isc	Vcc = +5.0 V, vs. GND		±15	±40	mA
Slew rate		$C_L = 10 \text{ pF}, R_L = 3 \text{ to } 7 \text{ k}\Omega$	1.5	9	30	V/μs
	SR	$C_L = 2500 \text{ pF}, R_L = 3 \text{ to } 7 \text{ k}\Omega$	1.5	4	30	V/μs
Propagation delay time Note 4	tphL tplH	$R_L = 3.5 \text{ k}\Omega, C_L = 2500 \text{ pF}$		0.8		μs
Output resistance	Ro	$V_{CC} = V_{DD} = V_{SS} = 0 V$ $V_{OUT} = \pm 2 V$	300	500		Ω
Standby output transition time	t DAZ	Note 5		4	10	μs
Standby output transition time	t dza	Note 5		25	50	ms

^{*} TYP.: Typical (reference) value at $T_A = 25$ °C.

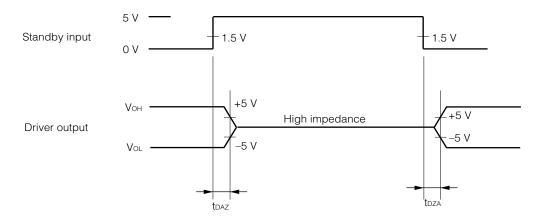


Note 4. Test point

If the output control pin is made low, the driver output goes low regardless of the driver input state.



Note 5. Test Point



Do not perform communication within the standby output transition time t_{DZA} on power application or on releasing the standby mode.



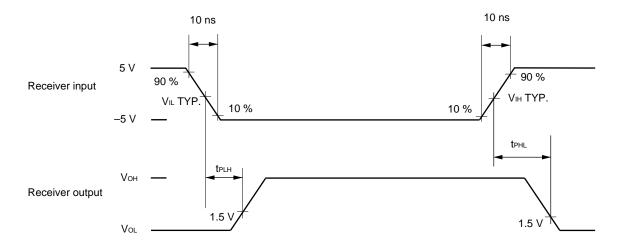
ELECTRICAL CHARACTERISTICS (RECEIVER) (Unless otherwise specified, Vcc = +5 V \pm 10 %, T_A = -20 °C to +80 °C, C₁ to C₄ = 22 μ F)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Low-level output voltage	Vol	louт = 4 mA			0.4	V
High-level output voltage	Vон	Ιουτ = −4 mA	Vcc			V
	VOH	IOUT = -4 IIIA	-0.8			V
Low-level input voltage	VIL	Rcon pin			0.8	V
High-level input voltage	Vıн	Rcon pin	2.0			V
Propagation delay time Note 7	t PHL	D 410 C 450 - F		0.40		
	t PLH	$R_L = 1 \text{ k}\Omega, C_L = 150 \text{ pF}$		0.13		μs
Input current	lin			1		mA
Input resistance	Rı		3	5	7	kΩ
Input pin release voltage	Vıo	Input threshold A mode only			0.5	V
Input threshold A mode	Vıн	Vcc = +5 V	1.6	2.2	2.6	V
(Rcon pin low)	VIL	Vcc = +5 V	0.6	1	1.6	V
	Vн	Vcc = +5 V (hysteresis width)	0.5	1.2	1.8	V
Input threshold B mode Note 6	ViH	Vcc = +5 V	1.6	2.2	2.6	V
(Rcon pin high)	VIL	Vcc = +5 V	-0.4	-1.8	-3.0	V
	Vн	Vcc = +5 V (hysteresis width)	2.6	4.0	5.4	V
Standby output transition time	tdaz	Note 8		0.4	1	μs
Standby output transiton time	t dza	Note 8		1	10	ms

^{*} TYP.: Typical (reference) value at $T_A = 25$ °C.

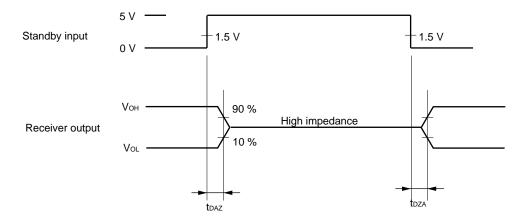
Note 6. This data is applicable to receivers 2 and 3 only. Receiver 1 is fixed in A mode.

Note 7. Test Point





Note 8. Test Point

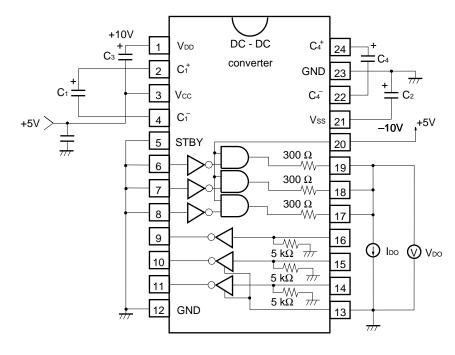


The receiver output is undefined during the standby output transition time tDZA. Do not perform communication in the standby output transition time tDZA on power application or on releasing the standby mode.

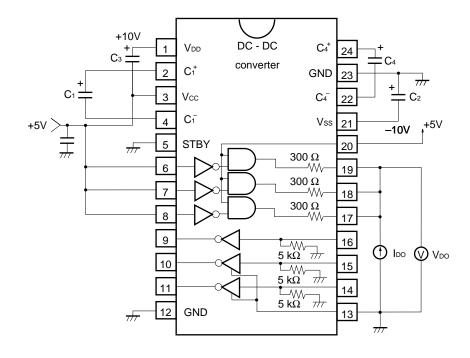


TEST CIRCUIT

Driver output voltage/Output current (+ side)



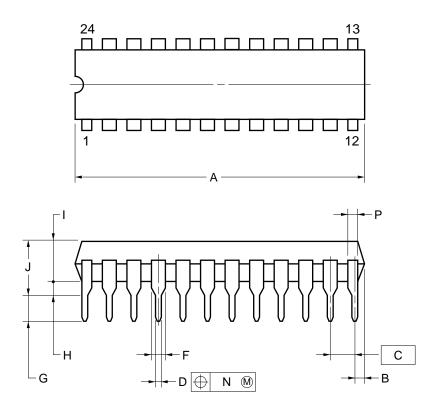
Driver output voltage/Output current (- side)

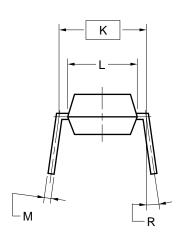




PACKAGE DRAWINGS

24PIN PLASTIC DIP (300 mil)





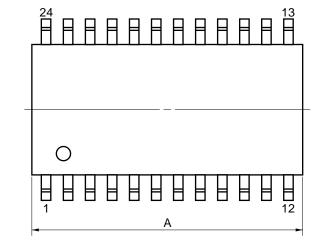
NOTES

- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

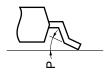
ITEM	MILLIMETERS	INCHES
Α	33.02 MAX.	1.300 MAX.
В	2.54 MAX.	0.100 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50±0.10	$0.020^{+0.004}_{-0.005}$
F	1.2 MIN.	0.047 MIN.
G	3.5±0.3	0.138±0.012
Н	0.51 MIN.	0.020 MIN.
1	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
М	$0.25^{+0.10}_{-0.05}$	$0.010^{+0.004}_{-0.003}$
N	0.25	0.01
Р	1.0 MIN.	0.039 MIN.
R	0~15°	0~15°
	-	D24C 100 200A 1

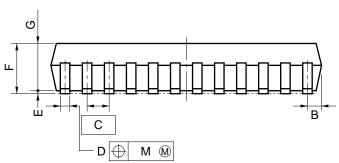
P24C-100-300A-1

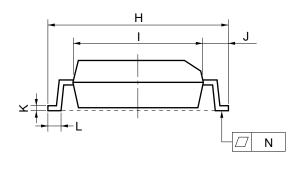
24 PIN PLASTIC SOP (375 mil)



detail of lead end







NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
Α	15.54 MAX.	0.612 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
E	0.1±0.1	0.004±0.004
F	2.9 MAX.	0.115 MAX.
G	2.50	0.098
Н	10.3±0.3	0.406+0.012
T	7.2	0.283
J	1.6	0.063
K	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.002}$
L	0.8±0.2	$0.031^{+0.009}_{-0.008}$
M	0.12	0.005
N	0.15	0.006
Р	3°+7°	3°+7°

P24GM-50-375B-3



RECOMMENDED SOLDERING CONDITIONS

Soldering the μ PD4713A under the conditions listed in the table below is recommended.

For soldering methods and conditions other than those recommended, consult NEC.

Surface mount type

For the details of the recommended soldering conditions of the surface mount type, refer to Information document "Semiconductor Device Mounting Technology Manual" (C10535EJ7V0IF00)

μ PD4713AGT

Soldering Method	Soldering Condition	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235 °C, Time: 30 seconds MAX.	IR35-00-2
	(210 °C MIN.), Number of times: 2, Number of days: not	
	limited*	
VPS	Package peak temperature: 215 °C, Time: 40 seconds MAX.	VP15-00-2
	(200 °C MIN.), Number of times: 2, Number of days: not	
	limited*	
Wave soldering	Soldering bath temperature: 260 °C MAX., Time: 10 seconds	WS60-00-1
	MAX., Number of times: 1, Number of days: not limited*	
Pin partial heating	Pin temperature: 300 °C MAX. (lead temperature), Time: 3	
	seconds MAX. (per lead pin), Number of days: not limited*	

^{*} The number of days the device can be stored at 25 °C, 65 % RH MAX. after the dry pack has been opened.

Caution Do not use two or more soldering methods in combination (except the pin partial heating method).

Throught-hole type

μ PD4713ACX

Soldering Method	Soldering Conditions
Wave soldering	Soldering bath temperature: 260 °C MAX., Time: 10 seconds MAX.

REFERENCE DOCUMENTS

"NEC Semiconductor Device Reliability/Quality Control System" (IEI-1212)

[&]quot;Quality Grade on NEC Semiconductor Devices" (IEI-1209)

[&]quot;Semiconductor Device Mounting Technology Manual" (C10535EJ7V0IF00)

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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Anti-radioactive design is not implemented in this product.

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